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Correspondence and requests for materials should be addressed to U.S. (udo. schwingenschlogl@ kaust.edu.sa)

Novel spectral features of nanoelectromechanical systems

M. Tahir¹, A. MacKinnon² & U. Schwingenschlögl¹

¹PSE Division, KAUST, Thuwal 23955-6900, Kingdom of Saudi Arabia, ²Department of Physics, The Blackett Laboratory, Imperial College London, South Kensington Campus, London SW7 2AZ, United Kingdom.

Electron transport through a quantum dot or single molecule coupled to a quantum oscillator is studied by the Keldysh nonequilibrium Green's function formalism to obtain insight into the quantum dynamics of the electronic and oscillator degrees of freedom. We tune the electronic level of the quantum dot by a gate voltage, where the leads are kept at zero temperature. Due to the nonequilibrium distribution of the electrons in the quantum dot, the spectral function becomes a function of the gate voltage. Novel spectral features are identified for the ground and excited states of nanomechanical oscillators that can be used to enhance the measurement sensitivity.

n the last decade, deeper understanding of a large class of systems important for electronic transport, such as molecular systems, has been accomplished by the single resonant level model. Electron transport through molecular single electron transistors has been a particularly hot topic in modern mesoscopic physics¹⁻⁴. The coupling of such a system to mechanical vibrations leads to important new physical phenomena, which have been demonstrated experimentally in many studies for molecular quantum dots, see Refs. 5–7, for example. In these experiments, the electron-phonon interaction is very strong and thus cannot be covered by perturbation theory. However, the quantum signatures of molecular vibrations have attracted much interest due to fundamental scientific challenges⁸⁻¹⁰ and potential applications in nanoelectromechanical systems (NEMS)^{11,12}.

NEMS have become a promising prototype for measuring the quantum behavior of nanoscale objects, theoretically as well as experimentally^{12,13}. The main motivation to study NEMS is the large number of potential applications in nanoelectronic devices, such as the measurement of very small masses, weak forces, and ultra small displacements of atomic positions^{11,14-17}. NEMS are also important from a fundamental point of view for understanding the transition between the classical and quantum regimes. This includes the observation, measurement, and control of quantum states of mesoscopic mechanical continuous variable systems, such as the quantum harmonic oscillator. Metallic leads coupled to the quantum dot have been successfully used to characterize the state of the mechanical resonator classically¹⁸ and quantum mechanically¹⁹. When the device is scaled down to the nanometer regime, the resonance frequencies increase and at the same time the effective masses decrease. Related applications are discussed in a very recent review in Ref. 20. Various electromechanical properties of the devices, such as current, conductance, and shot noise, are proportional to the spectral function. Hence, the spectral features²¹⁻²⁵ of the molecular systems are of great interest. In the latter studies, the spectral features have been discussed using the equation of motion and perturbative approximations for weak electron-phonon coupling. On the other hand, the spectral features of NEMS have not been discussed so far.

In view of the above, we study in this work the spectral function of a single quantum dot connected to two metallic leads and a quantum harmonic oscillator. An arbitrary voltage is applied to tune the single electronic level of the dot. The quantum oscillator is in the ground state and the leads are assumed to be in equilibrium at zero temperature. We address very small to very large chemical potential differences between the Fermi levels of the left and right leads, where the response to both Fermi levels is included in the calculations. The position of the resonant level with respect to the chemical potential in the leads is thus affected by the displacement of the nanomechanical oscillator, which in turn affects the transport properties of the tunnel junction. Electronic transport properties of similar systems have been discussed for a single electron transistor¹⁸ and a superconducting single electron transistor²⁶, both coupled to an oscillator. Both these studies have employed the quantum master equation approach within the weak coupling limit²⁰. It has been observed that, even though the leads are at zero temperature, the oscillator behaves as if it would be coupled to a bath/reservoir of finite temperature related to the chemical potential difference.

Here we employ the nonperturbative Green's function approach¹⁹⁻²⁴, as the recent experiments go beyond perturbation theory and thus a nonperturbative approach to the quantum master equation (equation of motion) is required. The Green's function approach allows us to consider strong electron-phonon coupling and has been applied successfully for very small up to very large applied bias. In contrast, the equation of motion approach^{18,25,26} treats both couplings as perturbations. In addition, this approach is valid only for high applied bias. We assume that quantum transport through the tunnel junction can be described by sequential tunneling. We note that the electron-oscillator interactions have been studied by scanning tunneling microscopy^{5,6,27-29} and spectroscopy^{7,29,30}. These methods turn out to be more valuable tools than the inelastic tunneling spectroscopy³¹⁻³³. In Refs. 34–39 it has been shown that the position of the single quantum dot energy level and the tunneling width, Γ , strongly affect the Kondo spectrum, where a third terminal has been used as a tip detector to measure the Kondo peaks. Spectral features of the Kondo effect have also been observed in the presence of strong electron-phonon interaction⁴⁰⁻⁴². In the present work, therefore, we will consider whether the intriguing features of NEMS can be explored by the spectral function.

Model formulation and the spectral function

We consider a single quantum dot connected to two identical metallic leads and apply a gate voltage. The single mode of the quantum oscillator is strongly coupled to the electrons on the dot. We neglect the spin degree of freedom, the electron-electron interaction, the effects of finite electron temperature of the leads and the damping of the oscillator. The Hamiltonian $H = H_{dot-ph} + H_{leads} + \Sigma_{\eta=L,R}$ $H_{\eta-dot}$ to be studied in the following is thus given by^{19,21-24}

$$H_{\text{dot-ph}} = \left[E_0 + \lambda \left(b^{\dagger} + b \right) \right] c_0^{\dagger} c_0 + \Omega b^{\dagger} b, \qquad (1)$$

where E_0 is the energy of the single electron level on the dot and c_0^{\dagger} , c_0 are the corresponding creation and annihilation operators. Moreover, λ is the coupling strength between the electrons on the dot and an oscillator of frequency Ω (setting $\hbar = 1$ for simplicity) and b^{\dagger} , b are the raising and lowering operators of the phonons. The remaining elements of the Hamiltonian are

$$H_{\text{leads}} = \sum_{\eta = L,R} \sum_{j=1}^{N} E_{\eta,j} c_{\eta,j}^{\dagger} c_{\eta,j}$$
(2)

$$H_{\eta\text{-dot}} = \frac{1}{\sqrt{N}} \sum_{j=1}^{N} V_{\eta} \left(c_{\eta,j}^{\dagger} c_0 + c_0^{\dagger} c_{\eta,j} \right), \tag{3}$$

where *N* is the total number of states in the lead and *j* counts the channels. We use the usual harmonic oscillator eigenfunctions $\Psi_n(x/\ell)$ when the electron is in the lead and $\Psi_n((x - x_0)/\ell)$ when it is on the dot, where ℓ is the zero point amplitude of the oscillator and $x_0 = \lambda \ell / \Omega$ is the displacement of the oscillator equilibrium position due to the coupling to the electrons. The Hamiltonian thus takes the form

$$H' = \begin{pmatrix} H'_{L} & V^{\dagger}_{L} & 0\\ V_{L} & H'_{\text{dot-ph}} & V_{R}\\ 0 & V^{\dagger}_{R} & H'_{R} \end{pmatrix},$$
(4)

where $H'_{\text{dot-ph}} = [E_0 + (n+1/2)\Omega - \Delta]\delta_{n,n'}, \quad H'_{\eta} = [E_{\eta,j} + (n+1/2)\Omega] \delta_{j,j'}\delta_{n,n'}, \text{ and } \Delta = \lambda^2/2\Omega \text{ is an energy shift.}$

In order to transform between the representations for the occupied and unoccupied dot we require the matrix elements

$$M_{m,n} = \ell^{-1} \int \Psi_m^*((x - x_0)/\ell) \Psi_n(x/\ell) \, dx \tag{5}$$

$$M_{m,n} = \sqrt{\frac{2^{|n-m|}\min[m,n]!}{\max[m,n]!}} \exp\left(-\frac{1}{4}x^2\right) \left(\frac{i}{2}x\right)^{|n-m|} \mathcal{L}_{\min[m,n]}^{|n-m|}\left(\frac{1}{2}x^2\right), (6)$$

where $x = x_0/\ell = \lambda/\Omega$. In addition, $L_m^n(x)$ are the associated Legendre polynomials.

The self-energy represents the contribution to the dot energy due to interaction between the dot and the leads it is coupled to. In the current model, with a single electronic state on the dot, there is no self-energy due to interaction. We use the wide-band approximation, where the self-energy contribution of each lead becomes energy independent and can be calculated as

$$\Sigma_{n,n,\eta}^{r}(\omega) = H_{\eta-\text{dot}}^{*}g_{\eta,\eta}^{r}\left(\omega - \left(n + \frac{1}{2}\right)\Omega\right) H_{\eta-\text{dot}},\tag{7}$$

where

$$g_{\eta,\eta}^{r}\left(\omega - \left(n + \frac{1}{2}\right)\Omega\right) \mapsto \frac{1}{N} \int_{-\infty}^{+\infty} \frac{N\rho_{\eta} dE_{\eta}}{\omega - \left(n + \frac{1}{2}\right)\Omega - E_{\eta}},\tag{8}$$

 ρ_{η} is the density of states in lead η (*L* or *R*), and $g_{\eta,\eta}^{r}(\omega)$ is the uncoupled retarded Green's function in the leads (recall that $\hbar = 1$). The retarded self-energy can hence be written as

$$\Sigma_{n,n,\eta}^{r}(\omega) = -\frac{i}{2}\Gamma_{\eta}.$$
(9)

Here $\Gamma_{\eta} = 4\pi |V_{\eta}|^2 \rho_{\eta}$ and Γ_{η} is the damping factor ($\Gamma_L = \Gamma_R = \Gamma$). The retarded self-energy is now independent of the oscillator index. Similarly

$$\Sigma_{n,n,\eta}^{a} = \left[\Sigma_{n,n,\eta}^{r}\right]^{*} = +\frac{i}{2}\Gamma_{\eta}.$$
(10)

We solve Dyson's equation using H_{η -dot as a perturbation. In the presence of the oscillator, the retarded and advanced Green's functions on the dot, with the phonon states in the representation of the unoccupied dot, may be written as

$$G_{n,n'}^{r/a}(\omega) = \sum_{m} M_{n,m} g_m^{r/a}(\omega) M_{n',m}^*,$$
(11)

where $g_m^{r/a}(\omega)$ is the retarded/advanced Green's function on the occupied dot obtained as

$$g_m^{r/a}(\omega) = \left[\omega - E_0 - \left(m + \frac{1}{2}\right)\Omega + \Delta \pm i\Gamma\right]^{-1}.$$
 (12)

The lesser Green's function in the presence of the nanomechanical oscillator including the dot and the leads is written as

$$G_{n,n'}^{<}(\omega) = \sum_{n_0,n_1} G_{n,n_0}^{r}(\omega) \Sigma_{n_0,n_1}^{<}(\omega) G_{n_1,n'}^{a}(\omega).$$
(13)

Here $\Sigma^{<}(\omega)$ is the lesser self-energy, given by

$$\Sigma^{<}(\omega) = \Sigma_{L}^{<}(\omega) + \Sigma_{R}^{<}(\omega), \qquad (14)$$

where the off-diagonal elements of the matrix $\Sigma_{\eta}^{<}(\omega)$ are zero and the diagonal elements may be written as

$$\Sigma_{n,n,\eta}^{<}(\omega) = i_{\eta} \int dE_{\eta} f_{\eta}(E_{\eta}) B_{n} \delta\left(\omega - E_{\eta} - \left(n + \frac{1}{2}\right)\Omega\right)$$

= $i\Gamma_{\eta} f_{\eta}(\varepsilon_{\eta}) B_{n0}.$ (15)

Here $\varepsilon = \omega - \left(n + \frac{1}{2}\right)\Omega$ and $f_{\eta}(\varepsilon_{\eta})$ denotes the Fermi distribution functions of the left and right leads, which have different chemical potentials under the bias, and B_n is the Boltzmann factor of the oscillator state. The index *n* determines the statistical occupation

probability of the phonon state $|n\rangle$ at finite temperature. Therefore, the accessibility of particular conduction channels is determined by a weight factor of the Boltzmann distribution function. For the present case of zero temperature the lesser self-energy may be recast in terms of the Heaviside step function $\theta(x)$ as

$$\Sigma_{n,n,\eta}^{<}(\omega) = i\Gamma\theta\left(E_{F_{\eta}} + \frac{1}{2}\Omega - \omega\right)\delta_{n,0},\tag{16}$$

where $E_{F_{\eta}}$ is the Fermi energy on lead η and the Kronecker delta, $\delta_{n,0}$, signifies that the nanomechanical oscillator is initially in its ground state, n = 0. All physical properties may be expressed in terms of the spectral function $A(\omega)$, which is at the heart of this paper. The spectral function is related to the imaginary part of the retarded or advanced Green's function^{21,22,25}

$$A(\omega) = -\operatorname{Im}[G^{r}(\omega)] = +\operatorname{Im}G^{a}(\omega), \qquad (17)$$

which we obtain as

$$A(\omega) = \sum_{m} \frac{2\Gamma M_{n,m} M_{n',m}^*}{\left[\omega - E_0 - \left(m + \frac{1}{2}\right)\Omega + \Delta\right]^2 + \Gamma^2},$$
(18)

where n = n' = 0 for the ground state and 1 for the first excited state of the nanomechanical oscillator. The spectral function is then used to calculate the differential conductance via the relation

$$I = \frac{e\Gamma}{4\pi} \int d\omega A(\omega) [f_L(\omega) - f_R(\omega)], \qquad (19)$$

where we have fixed the dot energy to $E_0 = 0.5$ and set the Fermi energy of the right lead to zero. The spectral function is proportional to the density of electron plus phonon states by the relation $n(\omega) =$ $A(\omega)/\pi$, which gives information about the excitations (electron or hole) of the system. The spectral function obtained in Eqs. (17) to (19) is the main result of the present work and the starting point for the subsequent discussion. The form of the spectral function obtained here makes the electronic and oscillator properties apparent as it is the essential ingredient for theoretical considerations on problems such as the high frequency behavior of nanomechanical oscillators, the current-voltage characteristics, quantum conductance, and shot noise phenomena^{21–25,34–42}.

Discussion

Analytical examination of Eq. (17) demonstrates a resonant peak for the purely electronic degree of freedom plus any number, *m*, of phonons. This discrete structure confirms the quantum mechanical



Figure 1 | Spectral function of the ground (n = 0, dotted line) and first excited (n = 1, solid line) states of the nanomechanical oscillator. The employed parameters (dimension of energy) are: $\Omega = 0.3$, $E_0 = 0.5$, $\lambda = 1.1\Omega$ and $\Gamma = 0.2\Omega$.



Figure 2 | Three-dimensional plot of the spectral function, as a function of ω and λ , for the ground state (n = 0) of the nanomechanical oscillator. The same parameters as in Fig. 1 are used.

aspect of the calculation^{18,26}. We expect the side peaks to be suppressed in the absence of electron-phonon coupling through $M_{m,n} = 0$ for $m \neq n$. In this regime, the resonant peak is shifted in energy by a constant shift, Δ , as shown in Eq. (17). In all the subsequent figures the following parameters are used with the dimension of energy: $\Omega = 0.3$, $E_0 = 0.5$, $\lambda = 1.1\Omega$, and $\Gamma = 0.2\Omega$.

We discuss the spectral function in Fig. 1 for the ground state (n = 0, dotted line) and the first excited state (n = 1, solid line) of the nanomechanical oscillator. We find n side peaks and a constant shift Δ consistent with Eqs. (4) and (17). This is the regime of strong coupling, $\lambda = 1.1\Omega$, whereas in the limit of weak coupling, $\lambda = 0.5\Omega$, we find a single side peak for the excited state. The amplitude of the side peaks becomes larger and the peaks sharper when the oscillator starts in the excited state instead of the ground state. We find a nontrivial feature for the first excited state of the nanomechanical oscillator, see the solid lines in Fig. 1: The first side peak is suppressed with a very small amplitude as compared to all other side peaks for strong electron-phonon coupling, which is not the case when the nanomechanical oscillator starts in its ground state (dotted lines in Fig. 1).

In order to explore this nontrivial behavior, we show in Figs. 2 and 3 three-dimensional plots of the spectral function, as a function of ω and the coupling strength λ , for the ground (n = 0) and excited (n = 1) states, respectively. We observe that valleys appear when the values of the excited state and integer values coming from the probability density function in Eq. (17) are the same. Closer examination of this equation shows that for m = 1 the side peaks are suppressed for different coupling strengths. Such a behavior is not possible in classical dynamics^{18,26} or any other perturbative approach used for molecular systems²¹⁻²⁵. Finally, we show the probability density $P(x) = M_{m,n}M_{n,m}^*$ calculated by Eq. (6) in Fig. 4 as a function of the



Figure 3 | Three-dimensional plot of the spectral function, as a function of ω and λ , for the first excited state (n = 1) of the nanomechanical oscillator. The same parameters as in Fig. 1 are used.



Figure 4 | Probability density as a function of the dimensionless coupling strength x for the ground (n = 0, dotted line) and first excited (n = 1, solid line) states of the nanomechanical oscillator. The same parameters as in Fig. 1 are used.

dimensionless coupling strength x to confirm the suppression of the side peaks. Results for the ground state and the first excited state of the nanomechanical oscillator are given by dotted and solid lines, respectively. From the solid line it is clear that when the oscillator starts in an excited state the curve approaches zero for n values of the coupling. Using Eq. (6), we obtain for the probability

$$P(x) \propto \left[\mathrm{L}_{1}^{0} \left(\frac{1}{2} \, x^{2} \right) \right]^{2}, \tag{20}$$

which can be simplified using for x > 0 the identity⁴⁴

$$L_n^m(x) = \frac{1}{\sqrt{\pi}} e^{x/2} x^{-(2m+1)/4} n^{(2m-1)/4} \cos\left(2\sqrt{nx} - \frac{(2m+1)\pi}{4}\right)_{(21)} + O\left(n^{(2m-3)/4}\right)$$

to yield

$$P(x) \propto \left[\frac{1}{\sqrt{\pi}} e^{x^2/4} \left(x^2/2\right)^{-1/4} \cos\left(\sqrt{2}x - \frac{\pi}{4}\right)\right]^2.$$
(22)

No such behavior has been reported for classical and perturbation treatments. The reason is that in the classical mechanics and perturbation approaches the oscillator does not couple strongly enough to the electrons on the dot. The nontrivial behavior only appears because a nonperturbative approach has been used in the present work. As compared to the existing literature, our nonperturbative approach is valid for small to large applied bias and can be employed for studying various problems in molecular systems^{1-4,21-25}, NEMS⁸⁻¹⁴, and shuttling transport⁴⁵⁻⁵².

The model considered in this work represents a nanomechanical oscillator coupled to a resonant tunnel junction, which can be directly used as small mass detector, sensor of ultra weak forces, and particularly as displacement detector^{8-12,19,20}. We propose to move from the quantum ground state of the nanomechanical oscillator to an excited state, because the resonant electronic peak will be suppressed and the mechanical side peaks will become sharper with larger amplitude. Due to the enhanced amplitude for strong electronoscillator coupling, the quality factor is enhanced, which increases the measurement sensitivity in the quantum regime⁵³⁻⁵⁸. The required excited state of the nanomechanical oscillator can be achieved by controlling the temperature as well as by applying an external gate. The application of NEMS often suffers from difficulties to control the damping in the systems. Various ways to overcome damping losses and, therefore, to improve the quality factor have been put forward both theoretically and experimentally, such as the parametric resonance^{53,54}, mechanical signal amplifying⁵⁵, sideband cooling^{56,57}, and the quantum behavior of macroscopic systems⁵⁸. The enhanced amplitude of the sidebands in the presence of strong electron-oscillator coupling for the excited state, as demonstrated in the present work, gives rise to an alternative and very efficient approach for increasing the measurement sensitivity of NEMS.

We have analyzed the spectral features of a quantum dot coupled to a nanomechanical oscillator by using the nonequilibrium Green's function approach, i.e., without treating the electron-phonon coupling as a perturbation. We have derived analytical expressions for the self-energies of the dot and the leads as well as the full Green's function. This enables us to investigate the effects of the coupling of the electrons to the oscillator on the dot and the tunneling rate of the electrons. Our numerical results show additional peaks in the spectrum for strong coupling to the single phonon mode. We find nontrivial dynamics of the nanomechanical oscillator, as reflected by a suppression of the first side peak in the spectrum when the oscillator starts in its first excited state. This effect could not be revealed by a classical or perturbation treatment of the oscillator. While both for the ground and excited states the side peaks are well resolved, they are enhanced in amplitude and sharper for the first excited state with respect to the ground state. Our method goes beyond perturbation theory and thus can be applied from small to large applied bias. It should turn out to be fruitful for various problems in molecular systems, NEMS, and shuttling transport phenomena. The theoretical framework developed in the present work for describing the ground and excited states of NEMS provides both reliable predictions of experiments and improved understanding of the circumstances under which nanomechanical systems are governed by quantum behavior.

- Park, H. *et al.* Nanomechanical oscillations in a single-C₆₀ transistor. *Nature* 407, 57–60 (2000).
- Postma, H. W. C., Teepen, T., Yao, Z., Grifoni, M. & Dekker, C. Carbon nanotube single-electron transistors at room temperature. *Science* 239, 76–79 (2001).
- Nitzan, A. & Ratner, M. A. Electron transport in molecular wire junctions. Science 300, 1384–1389 (2003).
- Galperin, M., Ratner, M. A. & Nitzan, A. Molecular transport junctions: Vibrational effects. J. Phys.: Condens. Matter 19, 103201 (2007).
- Qiu, X. H., Nazin, G. V. & Ho, W. Vibronic states in single molecule electron transport. *Phys. Rev. Lett.* 92, 206102 (2004).
- Repp, J., Meyer, G., Stojković, S. M., Gourdon, A. & Joachim, C. Molecules on insulating films: Scanning-tunneling microscopy imaging of individual molecular orbitals. *Phys. Rev. Lett.* **94**, 026803 (2005).
- Repp, J., Meyer, G., Paavilainen, S., Olsson, F. E. & Persson, M. Scanning tunneling spectroscopy of Cl vacancies in NaCl films: atrong electron-phonon coupling in double-barrier tunneling junctions. *Phys. Rev. Lett.* 95, 225503 (2005).
- 8. Blencowe, M. Quantum physics: Uncertain future. *Nature* **424**, 262–263 (2003).
- Martin, I., Shnirman, A., Tian, L. & Zoller, P. Ground-state cooling of mechanical resonators. *Phys. Rev. B* 69, 125339 (2004).
- 10. Blencowe, M. Nanomechanical quantum limits. Science 304, 56-57 (2004).
- LaHaye, M. D., Buu, O., Camarota, B. & Schwab, K. C. Approaching the quantum limit of a nanomechanical resonator. *Science* 304, 74–77 (2004).
- Schwab, K. C. & Roukes, M. L. Putting mechanics into quantum mechanics. *Phys. Today* 58, 36–42 (2005).
- Clerk, A. A., Girvin, S. M., Marquardt, F. & Schoelkopf, R. J. Introduction to quantum noise, measurement, and amplification. *Rev. Mod. Phys.* 82, 1155–1208 (2010).
- Yang, Y., Callegari, C., Feng, X., Ekinci, K. & Roukes, M. Zeptogram-scale nanomechanical mass sensing. *Nano Lett.* 6, 583–586 (2006).
- 15. Mamin, H. & Rugar, D. Sub-attonewton force detection at millikelvin temperatures. *Appl. Phys. Lett.* **79**, 3358 (2001).
- Lassagne, B., Tarakanov, Y., Kinaret, J., Sanchez, D. G. & Bachtold, A. Coupling mechanics to charge transport in carbon nanotube mechanical resonators. *Science* 325, 1107–1110 (2009).
- 17. Steele, G. A. *et al.* Strong coupling between single-electron tunneling and nanomechanical motion. *Science* **325**, 1103–1107 (2009).
- Armour, A. D., Blencowe, M. P. & Zhang, Y. Classical dynamics of a nanomechanical resonator coupled to a single-electron transistor. *Phys. Rev. B* 69, 125313 (2004).
- 19. Tahir, M. & MacKinnon, A. Quantum transport in a resonant tunnel junction coupled to a nanomechanical oscillator. *Phys. Rev. B* 77, 224305 (2008).



- 20. Poot, M. & Zant, H. S. J. v. d. Mechanical systems in the quantum regime. Physics Reports 511, 273-335 (2012).
- 21. Flensberg, K. Tunneling broadening of vibrational sidebands in molecular transistors. Phys. Rev. B 68, 205323 (2003).
- 22. Ryndyk, D. A. & Keller, J. Inelastic resonant tunneling through single molecules and quantum dots: Spectrum modification due to nonequilibrium effects. Phys. Rev. B 71, 073305 (2005).
- 23. Zazunov, A. & Martin, T. Transport through a molecular quantum dot in the polaron crossover regime. Phys. Rev. B 76, 033417 (2007).
- 24. Song, J., Sun, Q. F., Gao, J. & Xie, X. C. Measuring the phonon-assisted spectral function by using a nonequilibrium three-terminal single-molecular device. Phys. Rev. B 75, 195320 (2007).
- 25. Monreal, R. C. & Rodero, A. M. Equation of motion approach to the Anderson-Holstein hamiltonian. Phys. Rev. B 79, 115140 (2009).
- 26. Rodrigues, D. A., Imbers, J. & Armour, A. D. Quantum dynamics of a resonator driven by a superconducting single-electron transistor: A solid-state analogue of the micromaser. Phys. Rev. Lett. 98, 067204 (2007).
- 27. Stipe, B. C., Rezaei, M. A. & Ho, W. A variable-temperature scanning tunneling microscope capable of single-molecule vibrational spectroscopy. Rev. Sci. Instrum. 70, 137 (1999).
- 28. Stipe, B. C., Rezaei, M. A. & Ho, W. Localization of inelastic tunneling and the determination of atomic-scale structure with chemical specificity. Phys. Rev. Lett. 82, 1724 (1999).
- 29. Hahn, J. R., Lee, H. J. & Ho, W. Electronic resonance and symmetry in singlemolecule inelastic electron tunneling. Phys. Rev. Lett. 85, 1914 (2000).
- 30. Franke, K. J. & Pascual, J. I. Effects of electron-vibration coupling in transport through single molecules. J. Phys.: Condens. Matter 24, 394002 (2012).
- 31. Wang, W., Lee, T., Kretschmar, T. & Reed, M. A. Inelastic electron tunneling spectroscopy of an alkanedithiol self-assembled monolayer. Nano Lett. 4, 643-646 (2004).
- 32. Kushmerick, J. G. et al. Vibronic contributions to charge transport across molecular junctions. Nano Lett. 4, 639-642 (2004).
- 33. Wang, W., Lee, T. & Reed, M. A. Electron tunnelling in self-assembled monolayers. Rep. Prog. Phys. 68, 523 (2005).
- 34. Sun, Q. F. & Guo, H. Kondo resonance in a multiprobe quantum dot. Phys. Rev. B 64, 153306 (2001).
- 35. Lebanon, E. & Schiller, A. Measuring the out-of-equilibrium splitting of the Kondo resonance. Phys. Rev. B 65, 035308 (2002).
- 36. Franceschi, S. D. et al. Out-of-equilibrium Kondo effect in a mesoscopic device. Phys. Rev. Lett. 89, 156801 (2002).
- 37. Leturcq, R. et al. Probing the Kondo density of states in a three-terminal quantum ring. Phys. Rev. Lett. 95, 126603 (2005).
- 38. Liang, W., Shores, M. P., Bockrath, M., Long, J. R. & Park, H. Kondo resonance in a single-molecule transistor. Nature 417, 725-729 (2002).
- 39. Yu, L. H. et al. Kondo resonances and anomalous gate dependence in the electrical conductivity of single-molecule transistors. Phys. Rev. Lett. 95, 256803 (2005).
- 40. Park, J. et al. Coulomb blockade and the Kondo effect in single-atom transistors. Nature 417, 722-725 (2002).
- 41. Reed, M. A., Zhou, C., Muller, C. J., Burgin, T. P. & Tour, J. M. Conductance of a molecular junction. Science 278, 252-254 (1997).
- 42. Zhitenev, N. B., Meng, H. & Bao, Z. Conductance of small molecular junctions. Phys. Rev. Lett. 88, 226801 (2002).

- 43. Gradshteyn, I. S. & Ryzhik, I. M. Tables of Integrals, Series and Products 837 (Academic, New York, 1980).
- 44. Gradshteyn, I. S. & Ryzhik, I. M. Tables of Integrals, Series and Products 1039 (Academic, New York, 1980).
- 45. Nishiguchi, N. Shot-noise-induced random telegraph noise in shuttle current. Phys. Rev. Lett. 89, 066802 (2002).
- 46. Smirnov, A. Y., Mourokh, L. G. & Horing, N. J. M. Nonequilibrium fluctuations and decoherence in nanomechanical devices coupled to the tunnel junction. Phys. Rev. B 67, 115312 (2003).
- 47. Clerk, A. A. & Girvin, S. M. Shot noise of a tunnel junction displacement detector. Phys. Rev. B 70, 121303(R) (2004).
- 48. Novotný, T., Donarini, A., Flindt, C. & Jauho, A. P. Shot noise of a quantum shuttle. Phys. Rev. Lett. 92, 248302 (2004).
- 49. Armour, A. D. & MacKinnon, A. Transport via a quantum shuttle. Phys. Rev. B 66, 035333 (2002).
- 50. Flindt, C., Novotný, T. & Jauho, A. P. Current noise in a vibrating quantum dot array. Phys. Rev. B 70, 205334 (2004).
- 51. Wabnig, J., Khomitsky, D. V., Rammer, J. & Shelankov, A. L. Statistics of charge transfer in a tunnel junction coupled to an oscillator. Phys. Rev. B 72, 165347 (2005)
- 52. Gorelik, L. Y. et al. Shuttle mechanism for charge transfer in coulomb blockade nanostructures. Phys. Rev. Lett. 80, 4526 (1998).
- 53. Midtvedt, D., Tarakanov, Y. & Kinaret, J. Parametric resonance in
- nanoelectromechanical single electron transistors. Nano Lett. 11, 1439-1442 (2011). 54. Bergeal, N. et al. Analog information processing at the quantum limit with a Josephson ring modulator. Nat. Phys. 6, 296-302 (2010).
- 55. Lassagne, B., Tarakanov, Y., Kinaret, J., Sanchez, D. G. & Bachtold, A. Coupling mechanics to charge transport in carbon nanotube mechanical resonators. Science 325, 1107-1110 (2009).
- 56. Teufel, J. D. et al. Sideband cooling of micromechanical motion to the quantum ground state. Nature 475, 359-363 (2011).
- 57. Verhagen, E., Deleglise, S., Weis, S., Schliesser, A. & Kippenberg, T. J. Quantumcoherent coupling of a mechanical oscillator to an optical cavity mode. Nature 482, 63-67 (2012).
- 58. Peano, V. & Thorwart, M. Macroscopic quantum effects in a strongly driven nanomechanical resonator. Phys. Rev. B 70, 235401 (2004).

Author contributions

M.T., A.M. and U.S. wrote the manuscript.

Additional information

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